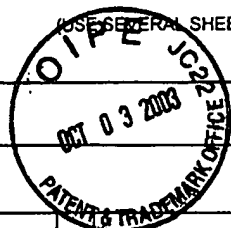


FORM PTO-1449	U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE	ATTY. DOCKET NO. MICRON.109DC1D1	APPLICATION NO. 10/614,538
SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT BY APPLICANT (USE SEVERAL SHEETS IF NECESSARY)		APPLICANT Chen, et al.	
		FILING DATE July 3, 2003	GROUP <u>Unknown</u> 2813



U.S. PATENT DOCUMENTS							
EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE (IF APPROPRIATE)
<i>MB</i>	1	US 5,498,569	03/1996	Eastep, Brian			
<i>MB</i>	2	US 5,654,233	08/1997	Yu, Chen-Hua Douglas			
<i>MB</i>	3	US 6,150,214	11/2000	Kaeriyama, Toshiyuki			
<i>MB</i>	4	US 6,184,117 B1	02/2001	Lu, King Yu			
<i>MB</i>	5	US 6,187,617 B1	02/2001	Gauthier et al.			
<i>MB</i>	6	US 6,358,788 B1	03/2002	Chen et al.			
<i>MB</i>	7	US 6,455,906 B2	09/2002	Chen et al.			
<i>MB</i>	8	US 6,541,830	04/2003	Iyer, Ravi			
	9						
	10						
	11						

FOREIGN PATENT DOCUMENTS								
EXAMINER INITIAL		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
							YES	NO
	12							
	13							
	14							
	15							
	16							

EXAMINER INITIAL	OTHER DOCUMENTS (INCLUDING AUTHOR, TITLE, DATE, PERTINENT PAGES, ETC.)						
	17						
	18						
	19						
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EXAMINER <i>[Signature]</i>	DATE CONSIDERED <i>7/2/04</i>
*EXAMINER: INITIAL IF CITATION CONSIDERED, WHETHER OR NOT CITATION IS IN CONFORMANCE WITH MPEP 609; DRAW LINE THROUGH CITATION IF NOT IN CONFORMANCE AND NOT CONSIDERED. INCLUDE COPY OF THIS FORM WITH NEXT COMMUNICATION TO APPLICANT.	

FORM PTO-1449	U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE	ATTY. DOCKET NO. MICRON.109DC1D1	APPLICATION NO. Unknown 10/614538
INFORMATION DISCLOSURE STATEMENT BY APPLICANT		APPLICANT Gary Chen et al.	
(USE SEVERAL SHEETS IF NECESSARY)		FILING DATE Herewith 7/3/03	GROUP Unknown 2813

U.S. PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE (IF APPROPRIATE)
<i>JMS</i>	1	3,968,565	07/13/76	Bertens et al.			
<i>JMS</i>	2	4,528,066	07/09/85	Merkling, Jr., et al.			
<i>JMS</i>	3	4,554,050	11/19/85	Minford, et al.			
<i>JMS</i>	4	4,671,852	06/9/87	Pyke			
<i>JMS</i>	5	4,787,958	11/29/88	Lytle			
<i>JMS</i>	6	4,900,690	02/13/90	Tamura			
<i>JMS</i>	7	5,023,201	06/11/91	Stanasolovich et al.			
<i>JMS</i>	8	5,100,826	03/31/92	Dennison			
<i>JMS</i>	9	5,198,384	03/30/93	Dennison			
<i>JMS</i>	10	5,202,287	04/13/93	Joshi et al.			
<i>JMS</i>	11	5,425,392	06/20/95	Thakur, et al.			
<i>JMS</i>	12	5,462,638	10/31/95	Datta, et al.			
<i>JMS</i>	13	5,498,293	03/12/96	Ilardi et al.			
<i>JMS</i>	14	5,712,168	01/27/98	Schmidt, et al.			
<i>JMS</i>	15	5,798,296	08/26/98	Fazan, et al.			
<i>JMS</i>	16	5,800,726	09/01/98	Cotte, et al.			
<i>JMS</i>	17	5,801,425	09/01/98	Kuroi et al.			
<i>JMS</i>	18	5,814,560	09/29/98	Cheung et al.			
<i>JMS</i>	19	5,830,798	11/03/98	Dennison, et al.			
<i>JMS</i>	20	5,888,894	03/30/99	Kong, et al.			
<i>JMS</i>	21	5,907,791	05/25/99	Cappuzzo et al.			
<i>JMS</i>	22	5,989,354	11/23/99	Dormer et al.			
<i>JMS</i>	23	5,960,303	09/28/99	Hill			
<i>JMS</i>	24	6,010,965	01/04/00	Shields			
<i>JMS</i>	25	6,015,505	01/18/00	David et al.			
<i>JMS</i>	26	6,136,211	10/24/00	Qian et al.			

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DATE CONSIDERED

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FORM PTO-1449 U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE INFORMATION DISCLOSURE STATEMENT BY APPLICANT (USE SEVERAL SHEETS IF NECESSARY)	ATTY. DOCKET NO. MICRON.109DC1D1		APPLICATION NO. Unknown 10/614538	
	APPLICANT Gary Chen et al.			
	FILING DATE Herewith 7/3/03		GROUP Unknown 2813	

U.S. PATENT DOCUMENTS							
EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE (IF APPROPRIATE)
<i>JMS</i>	27	6,221,746	04/24/01	Huang et al.			
<i>JMS</i>	28	6,417,572	07/09/02	Chidambarao et al.			

FOREIGN PATENT DOCUMENTS								
EXAMINER INITIAL		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
							YES	NO
JMS	29	0 560 324 A1	09/15/93	Europe				

EXAMINER INITIAL	OTHER DOCUMENTS (INCLUDING AUTHOR, TITLE, DATE, PERTINENT PAGES, ETC.)						
<i>JMS</i>	30	Silicon Processing for the VLSI Era - Volume 1: Process Technology, Stanley Wolf and Richard N. Tauber, Lattice Press, Sunset Beach, California					
<i>JMS</i>	31	US Publication No. US 2001/0003062 A1, Inventor: Rebecca Y. Tang, Pub. Date: June 7, 2001, Title: GATE SIDEWALL PASSIVATION TO PREVENT ABNORMAL TUNGSTEN POLYCIDAL GROWTH					
<i>JMS</i>	32	US Publication No. US 2001/0019894 A1, Inventors: Peng et al., Pub Date: September 6, 2001, Title: PRE-HEAT STEP (OR CHAMBER) IMPLEMENTED IN PR DRY ASH MACHINES TO EFFECTIVELY ELIMINATE PR EXTRUSION (BUBBLE) AFTER ALLOY					

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